4-Bit Magnitude Comparator

The SN74LS85 is a 4-Bit Magnitude Camparator which compares two 4-bit words (A, B), each word having four Parallel Inputs (A₀-A₃, B₀-B₃); A₃, B₃ being the most significant inputs. Operation is not restricted to binary codes, the device will work with any monotonic code. Three Outputs are provided: "A greater than B" $(O_{A>B})$, "A less than B" $(O_{A<B})$, "A equal to B" $(O_{A=B})$. Three Expander Inputs, I_{A>B}, I_{A<B}, I_{A=B}, allow cascading without external gates. For proper compare operation, the Expander Inputs to the least significant position must be connected as follows: $I_{A < B} = I_{A > B} = L_{a}$ $I_{A=B} = H$. For serial (ripple) expansion, the $O_{A>B}$, $O_{A<B}$ and $O_{A=B}$ Outputs are connected respectively to the $I_{A>B}$, $I_{A<B}$, and $I_{A=B}$ Inputs of the next most significant comparator, as shown in Figure 1. Refer to Applications section of data sheet for high speed method of comparing large words.

The Truth Table on the following page describes the operation of the SN74LS85 under all possible logic conditions. The upper 11 lines describe the normal operation under all conditions that will occur in a Max Uni⁴ 5.25 single device or in a series expansion scheme. The lower five lines describe the operation under abnormal conditions on the cascading inputs. These conditions occur when the parallel expansion technique is used.

- Easily Expandable
- Binary or BCD Comparison
- $O_{A>B}$, $O_{A<B}$, and $O_{A=B}$ Outputs Available

GOAIIAN	TEED OF EIRAING HANG					
Symbol	Parameter	Min	Тур	Max	Unit	
V _{CC}	Supply Voltage	4.75	5.0	5.25	V	
T _A	Operating Ambient Temperature Range	0	25	70	°C	
I _{OH}	Output Current – High	6		-0.4	mA	
I _{OL}	Output Current – Low	5		8.0	mA	
	PLEA	R				

GUARANTEED OPERATING RANGES



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LOW POWER SCHOTTKY



CASE 648

SOIC **D SUFFIX** CASE 751B



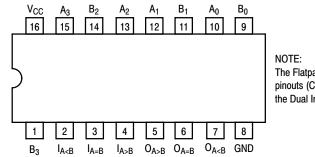
M SUFFIX CASE 966

ORDERING INFORMATION

Device	Package	Shipping		
SN74LS85N	16 Pin DIP	2000 Units/Box		
SN74LS85D	SOIC-16	38 Units/Rail		
SN74LS85DR2	SOIC-16	2500/Tape & Reel		
SN74LS85M	SOEIAJ-16	See Note 1		
SN74LS85MEL	SOEIAJ-16	See Note 1		

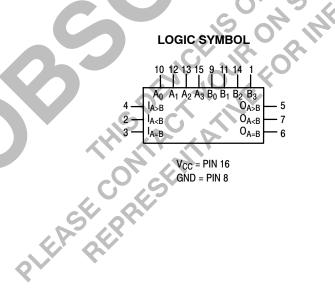
1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

CONNECTION DIAGRAM DIP (TOP VIEW)

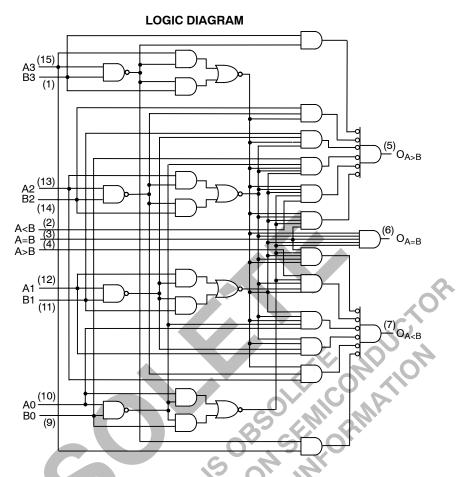


The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

	_	LOADING	(Note a)	_
PIN NAMES		HIGH	LOW	_
A ₀ - A ₃ , B ₀ - B ₃	Parallel Inputs	1.5 U.L.	0.75 U.L.	-
I _{A = B}	A = B Expander Inputs	1.5 U.L.	0.75 U.L.	^
I _{A < B} , I _{A > B}	A < B, A > B, Expander Inputs	0.5 U.L.	0.25 U.L.	
O _{A > B}	A Greater than B Output	10 U.L.	5 U.L.	
O _{A < B}	B Greater than A Output	10 U.L.	5 U.L.	
O _A = B	A Equal to B Output	10 U.L.	5 U.L.	
NOTES: a) 1 TTL Unit L	oad (U.L.) = 40 μΑ HIGH/1.6 mA	LOW.	INCON INCON	ATION
	LOGIC SYMBOL			
		40°		



NOTES:



TRUTH TABLE

				TI	RUTH T	ABLE				
	COMPARING INPUTS				SCADIN NPUTS	IG O	OUTPUTS			
A	A ₃ ,B ₃	A ₂ ,B ₂	A ₁ ,B ₁	A ₀ ,B ₀	I _{A>B}	I _{A<b< sub=""></b<>}	I _{A=B}	O _{A>B}	O _{A<b< sub=""></b<>}	O _{A=B}
A	_{3>} B ₃	X	Х	X	X	X	X	Н	L	L
A	₃ <b<sub>3</b<sub>	x	Х	2 X	X	X	Х	L	Н	L
A	_{3=B3}	$A_2 > B_2$	Х	Х	X	X	Х	Н	L	L
A	_{3=B3}	$A_2 < B_2$	X	Х	X	Х	Х	L	Н	L
	_{3=B3}	$A_2 = B_2$	A ₁ >B ₁	X	X	Х	Х	Н	L	L
A		$A_2 = B_2$	A1 <b1< td=""><td>X</td><td>X</td><td>Х</td><td>Х</td><td>L</td><td>Н</td><td>L</td></b1<>	X	X	Х	Х	L	Н	L
A	₃ =B ₃	$A_2 = B_2$	A ₁ =B1	$A_0 > B_0$	Х	Х	Х	Н	L	L
A	₃₌ B ₃	$A_2=B_2$	A1=B1	A ₀ <b<sub>0</b<sub>	Х	Х	Х	L	Н	L
		A ₂ =B ₂	A ₁ =B ₁	$A_0 = B_0$	Н	L	L	Н	L	L
A	₃₌ B ₃	$A_2 = B_2$	A1=B1	$A_0 = B_0$	L	Н	L	L	Н	L
A	₃ =B ₃ ,	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	Х	Х	Н	L	L	Н
A	₃ =B ₃	$A_2=B_2$	$A_1 = B_1$	$A_0 = B_0$	Н	Н	L	L	L	L
A	_{3=B3}	$A_2 = B_2$	$A_1 = B_1$	$A_0 = B_0$	L	L	L	Н	Н	L

H = HIGH Level L = LOW Level X = IMMATERIAL

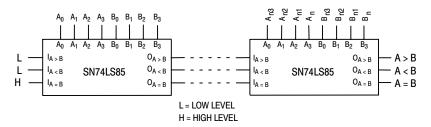


Figure 1. Comparing Two n-Bit Words

APPLICATIONS

Figure 2 shows a high speed method of comparing two 24-bit words with only two levels of device delay. With the technique shown in Figure 1, six levels of device delay result

when comparing two 24-bit words. The parallel technique can be expanded to any number of bits, see Table 1.

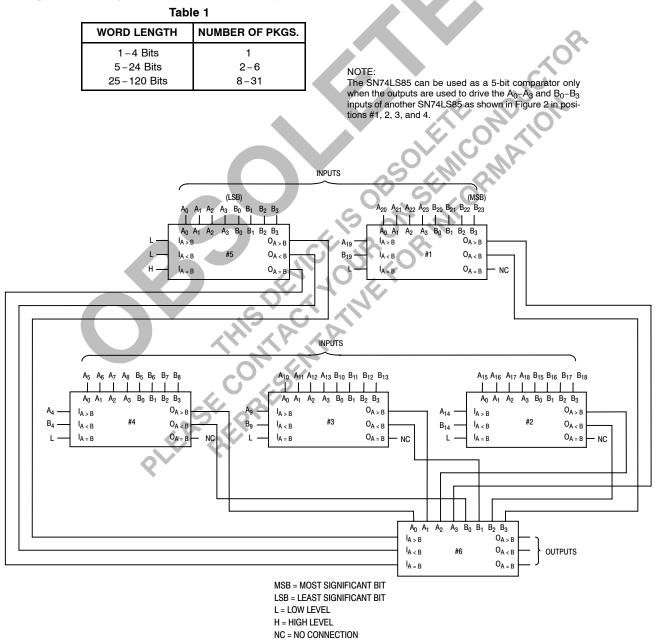


Figure 2. Comparison of Two 24-Bit Words

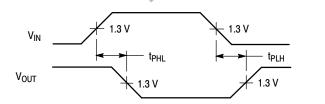
DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE	(unless otherwise specified)
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		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V_{CC} = MIN, I_{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V _{CC} = MIN, I _{OH} = or V _{IL} per Truth T	= MAX, V _{IN} = V _{IH} īable	
.,	Output LOW Voltage		0.25	0.4	V	l _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}			0.35	0.5	V	l _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
IIH	Input HIGH Current A < B, A > B Other Inputs			20 60	μΑ	V_{CC} = MAX, V_{IN}	= 2.7 V	
	A < B, A > B Other Inputs			0.1 0.3	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
IIL	Input LOW Current A < B, A > B Other Inputs			-0.4 -1.2	mA	V _{CC} = MAX, V _{IN}	= 0.4 V	
I _{OS}	Output Short Circuit Current (Note 2)	-20		-100	mA	V _{CC} = MAX		
	Power Supply Current			20	mA	V _{CC} = MAX		

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

2. Not more th	an one output should be shorted at a tin	ne, nor fo	r more th	an 1 seco	ond.	N' All
AC CHARAC	TERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)			<u> </u>	29	60
			Limits	2 C		
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Any A or B to A < B, A > B	7.	24 20	36 30	ns	
t _{PLH} t _{PHL}	Any A or B to A = B		27 23	45 45	ns	
t _{PLH} t _{PHL}	A < B or A = B to A > B		14 11	22 17	ns	V _{CC} = 5.0 V C _L = 15 pF
t _{PLH} t _{PHL}	A = B to A = B	S	13 13	20 26	ns	
t _{PLH} t _{PHL}	A > B or A = B to A < B		14 11	22 17	ns	

AC WAVEFORMS



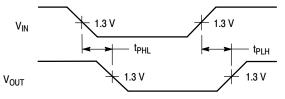
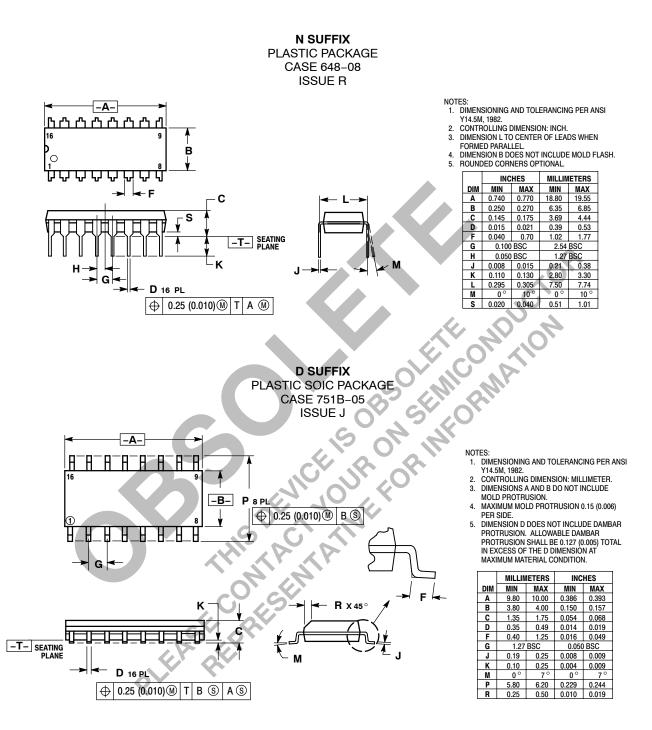


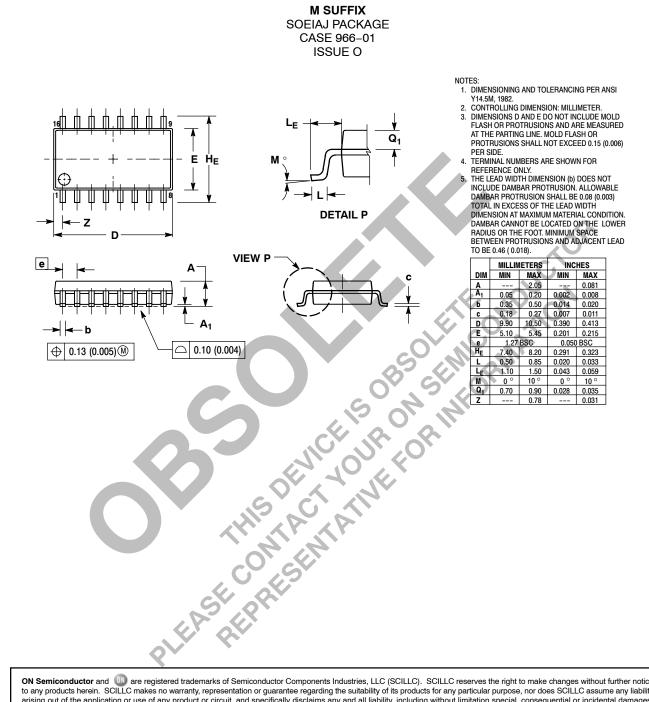
Figure 3.

Figure 4.

PACKAGE DIMENSIONS



PACKAGE DIMENSIONS



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